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October 2013

FDP2614

N-Channel PowerTrench® MOSFET 200 V, 62 A, 27 m Ω

Features

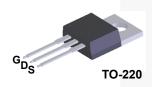
- $R_{DS(on)}$ = 22.9 m Ω (Typ.)@ V_{GS} = 10 V, I_D = 31 A
- · Fast Switching Speed
- · Low Gate Charge
- High Performance Trench technology for Extremely Low $R_{\mbox{\footnotesize{DS}}(\mbox{\footnotesize{on}})}$
- · High Power and Current Handing Capability
- RoHS Compliant

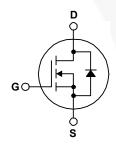
General Description

This N-Channel MOSFET is producedusing Fairchild Semiconductor's advanced PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- · Consumer Appliances
- Synchronous Rectification
- · Battery Protection Circuit
- · Motor Drives and Uninterruptible Power Supplies





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol		Parameter		FDP2614	Unit
V _{DS}	Drain-Source Voltage		200	V	
V _{GS}	Gate-Source Voltage		± 30	V	
I _D	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)		62 39.3	A A
I _{DM}	Drain Current	- Pulsed	(Note 1)	see Figure 9	A
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		145	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns	
P_{D}	Power Dissipation	Power Dissipation (T _C = 25°C) - Derate above 25°C		260 2.1	W W/°C
T _{J,} T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
T _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	FDP2614	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.48	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP2614	FDP2614	TO-220	Tube	N/A	50 units

Electrical Characteristics $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Off Charac	Off Characteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V$, $I_D = 250\mu A$, $T_J = 25^{\circ}C$	200			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C		0.2		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 200V, V _{GS} = 0V V _{DS} = 200V, V _{GS} = 0V, T _J = 125°C			10 500	μ Α μ Α
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30V, V _{DS} = 0V	-		100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30V, V _{DS} = 0V	-		-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0	4.0	5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10V, I _D = 31A		22.9	27	mΩ
9 _{FS}	Forward Transconductance	V _{DS} = 10V, I _D = 31A		72		S
Dynamic C	Characteristics					
C _{iss}	Input Capacitance			5435	7230	pF
C _{oss}	Output Capacitance	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz	\	505	675	pF
C _{rss}	Reverse Transfer Capacitance	- 1 - 1.0ivii iz		110	165	pF
Switching	Characteristics				_	
t _{d(on)}	Turn-On Delay Time			77	165	ns
t _r	Turn-On Rise Time	$V_{DD} = 100V, I_D = 62A$ $V_{GS} = 10V, R_{GEN} = 25\Omega$		284	560	ns
t _{d(off)}	Turn-Off Delay Time	3-1	-	103	220	ns
t _f	Turn-Off Fall Time	(Note 4)		162	335	ns
Qg	Total Gate Charge			76	99	nC
Q _{gs}	Gate-Source Charge	$V_{DS} = 100V, I_{D} = 62A$ $V_{GS} = 10V$	/	35		nC
Q _{gd}	Gate-Drain Charge	(Note 4)	-	18		nC
Drain-Sour	rce Diode Characteristics and Maximun	n Ratings	/			
I _S	Maximum Continuous Drain-Source Diode Forward Current				62	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current		-		186	Α
V_{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0V, I _S = 62A	-		1.2	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0V, I _S = 62A	-	145		ns
Q _{rr}	Reverse Recovery Charge	dI _F /dt =100A/μs		0.81		μС

Notes

^{1.} Repetitive Rating: Pulse width limited by maximum junction temperature

^{2.} L = 1mH, I_{AS} = 17A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25 $^{\circ}$ C

^{3.} $I_{SD} \le 62 \text{A}$, di/dt $\le 100 \text{A}/\mu\text{s}$, $V_{DD} \le \text{BV}_{DSS}$, Starting T_J = 25°C

^{4.} Essentially Independent of Operating Temperature Typical Characteristics

Typical Performance Characteristics

Figure 1. On-Region Characteristics

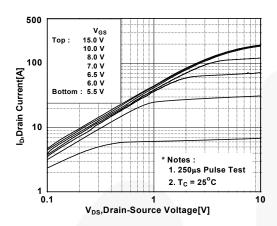


Figure 3. On-Resistance Variation vs. Drain
Current and Gate Voltage

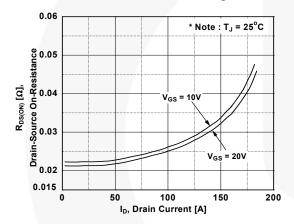


Figure 5. Capacitance Characteristics

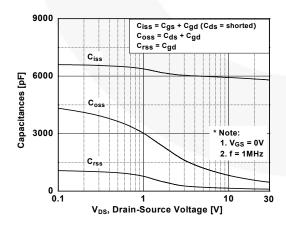


Figure 2. Transfer Characteristics

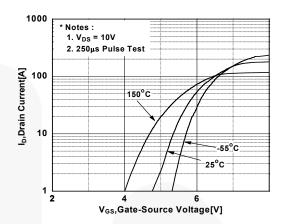


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

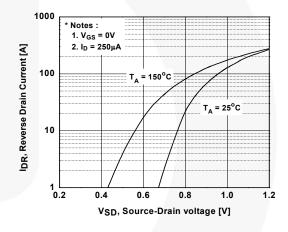
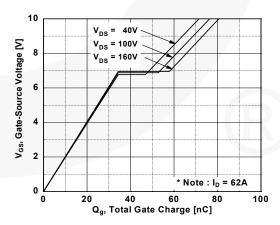


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. **Temperature**

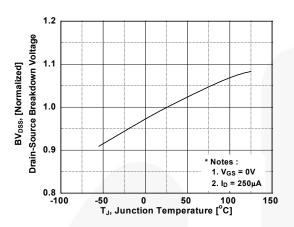


Figure 9. Maximum Safe Operating Area

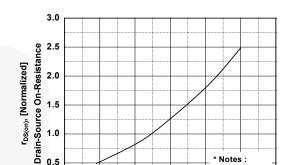


Figure 8. On-Resistance Variation vs. Tem-

perature

Figure 10. Maximum Drain Current vs. Case-**Temperature**

50

T_J, Junction Temperature [°C]

0

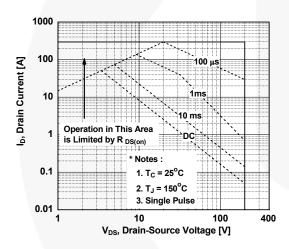
Notes:

100

1. V_{GS} = 10V

2. I_D = 31A

150



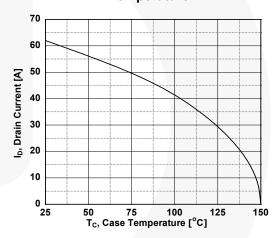


Figure 11. Transient Thermal Response Curve

0.0

-100

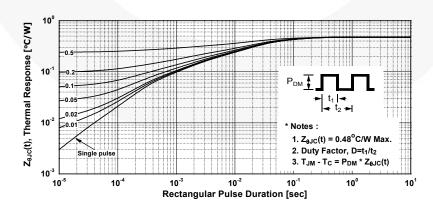


Figure 12. Gate Charge Test Circuit & Waveform

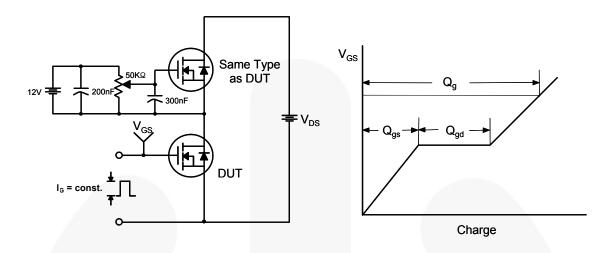


Figure 13. Resistive Switching Test Circuit & Waveforms

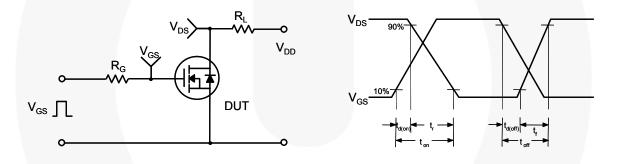
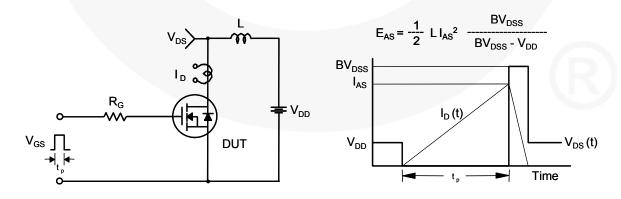
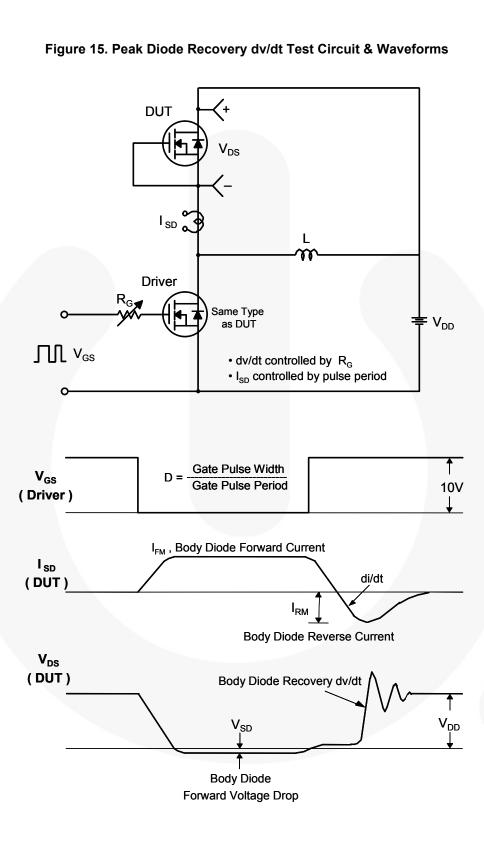


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms





Mechanical Dimensions

TO-220 3L

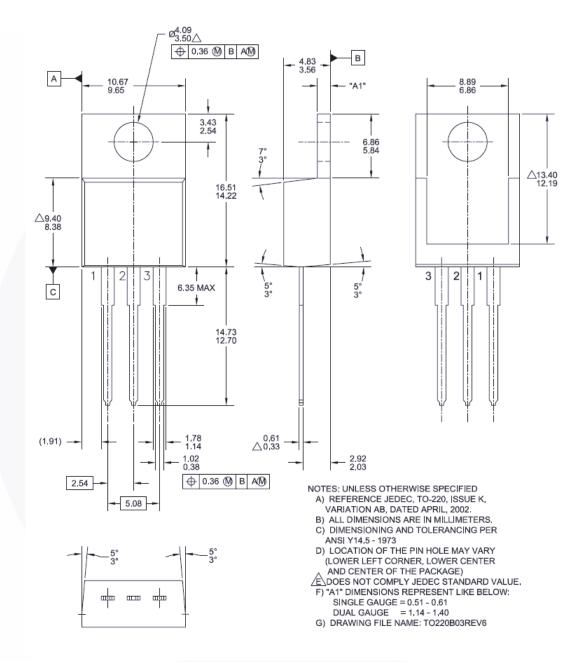


Figure 16. TO-220, Molded, 3Lead, Jedec Variation AB

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Dimension in Millimeters





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